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Microsemi.

# Power Matters<sup>™</sup>

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## 2N3053 (#23654)

#### Devil of Discrete

**Products** 

- ► Product Directory
- ► Applications Directory
- ▶ Parametric Search

### Overview Diagrams

Electrical Rating
Symbol Min Typ Max Unit
Collector to Emitter Saturation Voltage
V<sub>CE(sat)</sub>
1.40 V

DC Current Gain
HFE 50.00 250.00

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	V <sub>BR(CBO)</sub>			60.00	V
Collector Current (dc)	I <sub>C</sub>			0.70	Α
Collector-Emitter Voltage (Base Open)	$V_{CEO}$			40.00	V
Emitter-Base Voltage (Collector Open)	V <sub>EBO</sub>			5.00	V
Power Dissipation, Total	P <sub>T</sub>			5.00	W

This part can be found in the following product categories:

- → Discretes → Transistors → BJT( BiPolar Junction Transistor) → PNP Transistor
- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ PNP Transistor

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